

TIME SLOT INTERCHANGE DIGITAL SWITCH 2,048 x 2,048

FEATURES:

- 2,048 x 2,048 channel non-blocking switching at 8.192 Mb/s
- Per-channel variable or constant throughput delay
- Automatic identification of ST-BUS®/GCI interfaces
- Accept streams of 2.048 Mb/s, 4.096 Mb/s or 8.192 Mb/s
- Automatic frame offset delay measurement
- · Per-stream frame delay offset programming
- Per-channel high impedance output control
- Per-channel Processor Mode
- Control interface compatible to Intel/Motorola CPUs
- Connection memory block programming
- IEEE-1149.1 (JTAG) Test Port
- Available in 84-pin Plastic Leaded Chip Carrier (PLCC), 100-pin Ball Grid Array (BGA), 100-pin Plastic Quad Flatpack

FUNCTIONAL BLOCK DIAGRAM

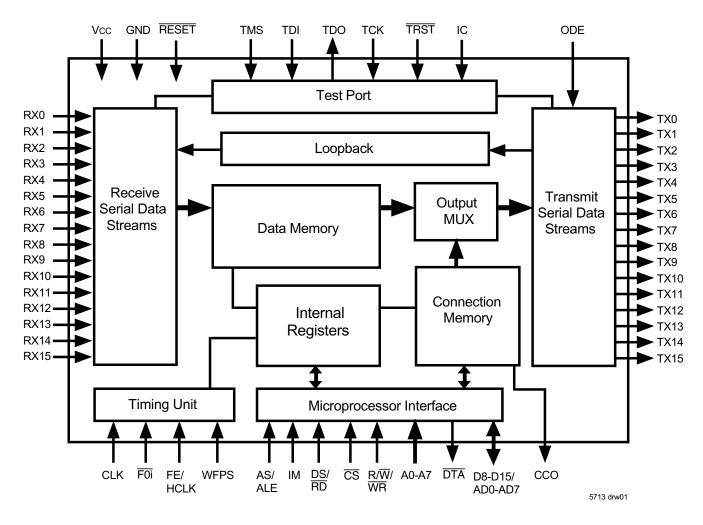
(PQFP) and 100-pin Thin Quad Flatpack (TQFP)

- Operating Temperature Range -40°C to +85°C
- 5V Power Supply

DESCRIPTION:

The IDT7290820 is a non-blocking digital switch that has a capacity of $2,048 \times 2,048$ channels at a serial bit rate of 8.192 Mb/s, $1,024 \times 1,024$ channels at 4.096 Mb/s and 512×512 channels at 2.048 Mb/s. Some of the main features are: programmable stream and channel control, Processor Mode, input offset delay and high-impedance output control.

Per-stream input delay control is provided for managing large multi-chip switches that transport both voice channel and concatenated data channels. In addition, input streams can be individually calibrated for input frame offset.

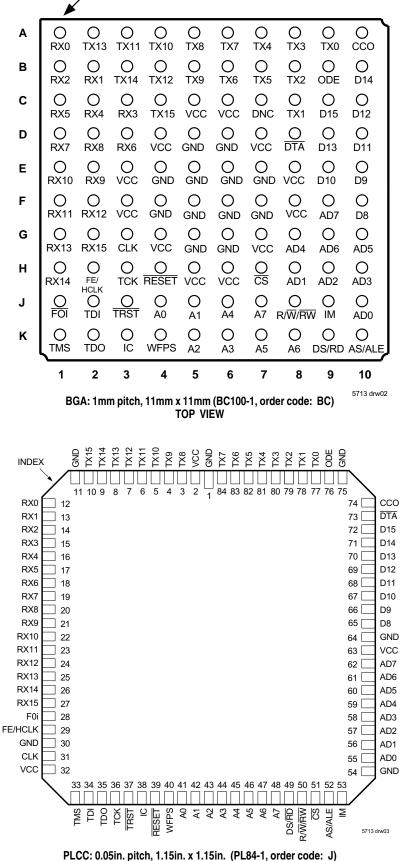


MARCH 2009

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PIN CONFIGURATIONS

____ A1 BALL PAD CORNER



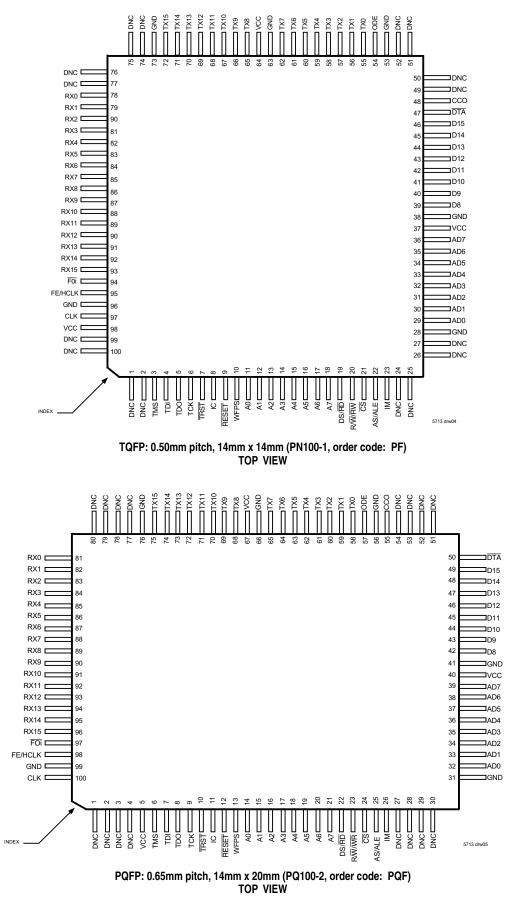
TOP VIEW

NOTES:

1. DNC - Do Not Connect

2. IC - Internal Connection, tie to GROUND for normal operation.

PIN CONFIGURATIONS (Continued)



PIN DESCRIPTION

SYMBOL	NAME	I/O	DESCRIPTION
GND	Ground.		Ground Rail.
Vcc	Vcc		+5.0 Volt Power Supply.
TX0-15 ⁽¹⁾	TX Output 0 to 15 (Three-state Outputs)	0	Serial data output stream. These streams may have data rates of 2.048, 4.096 or 8.192 Mb/s, depending upon the value programmed at bits DR0-1 in the IMS register.
RX0-15 ⁽¹⁾	RX Input 0 to 15	Ι	Serial data input stream. These streams may have data rates of 2.048, 4.096 or 8.192 Mb/s, depending upon the value programmed at bits DR0-1 in the IMS register.
F0i ⁽¹⁾	Frame Pulse	Ι	When the WFPS pin is LOW, this input accepts and automatically identifies frame synchronization signals formatted according to ST-BUS [®] and GCI specifications. When the WFPS pin is HIGH, this pin accepts a negative frame pulse which conforms to WFPS formats.
FE/HCLK ⁽¹⁾	Frame Evaluation/ HCLK Clock	Ι	When the WFPS pin is LOW, this pin is the frame measurement input. When the WFPS pin is HIGH, the HCLK (4.096 MHz clock) is required for frame alignment in the wide frame pulse (WFP) mode.
CLK ⁽¹⁾	Clock	Ι	Serial clock for shifting data in/out on the serial streams (RX/TX 0-15). Depending upon the value programmed at bits DR0-1 in the IMS register, this input accepts a 4.096, 8.192 or 16.384 MHz clock.
TMS	Test Mode Select	Ι	JTAG signal that controls the state transitions of the TAP controller. This pin is pulled HIGH by an internal pull- up when not driven.
TDI	Test Serial Data In	Ι	JTAG serial test instructions and data are shifted in on this pin. This pin is pulled HIGH by an internal pull-up when not driven.
TDO	Test Serial Data Out	0	JTAG serial data is output on this pin on the falling edge of TCK. This pin is held in high-impedance state when JTAG scan is not enabled.
TCK ⁽¹⁾	Test Clock	Ι	Provides the clock to the JTAG test logic. This pin is pulled high by an internal pull-up when not driven.
TRST	Test Reset	Ι	Asynchronously initializes the JTAG TAP controller by putting it in the Test-Logic-reset state. This pin is pulled by an internal pull-up when not driven. This pin should be pulsed LOW on power-up, or held LOW, to ensure that the IDT7290820 is in the normal functional mode.
IC ⁽¹⁾	Internal Connection	I	Connect to GND for normal operation. This pin must be LOW for the IDT7290820 to function normally and to comply with IEEE 1114 (JTAG) boundary scan requirements.
RESET ⁽¹⁾	Device Reset (Schmitt Trigger Input)	I	This input (active LOW) puts the IDT7290820 in its reset state that clears the device internal counters, registers and brings TX0-15 and microport data outputs to a high-impedance state. The time constant for a power up reset circuit must be a minimum of five times the rise time of the power supply. In normal operation, the RESET pin must be held LOW for a minimum of 100ns to reset the device.
WFPS ⁽¹⁾	Wide Frame Pulse Select	Ι	When 1, enables the wide frame pulse (WFP) Frame Alignment interface. When 0, the device operates in ST-BUS®/GCI mode.
A0-7 ⁽¹⁾	Address 0-7	Ι	When non-multiplexed CPU bus operation is selected, these lines provide the A0-A7 address lines to the internal memories.
DS/RD(1)	Data Strobe/Read	1	For Motorola multiplexed bus operation, this input is DS. This active HIGH DS input works in conjunction with \overline{CS} to enable the read and write operations. For Motorola non-multiplexed CPU bus operation, this input is DS. This active LOW input works in conjunction with \overline{CS} to enable the read and write operations. For Intel multiplexed bus operation, this input is \overline{RD} . This active LOW input sets the data bus lines (AD0-7, D8-15) as outputs.
R/W / WR ⁽¹⁾	Read/Write / Write	Ι	In the cases of Motorola non-multiplexed and multiplexed bus operations, this input is R/W. This input controls the direction of the data bus lines (AD0-7, D8-15) during a microprocessor access. For Intel multiplexed bus operation, this input is WR. This active LOW input is used with RD to control the data bus (AD0-7) lines as inputs.
CS ⁽¹⁾	Chip Select	Ι	Active LOW input used by a microprocessor to activate the microprocessor port of IDT7290820.
AS/ALE ⁽¹⁾	Address Strobe or Latch Enable	Ι	This input is used if multiplexed bus operation is selected via the IM input pin. For Motorola non-multiplexed bus operation, connect this pin to ground. This pin is pulled low by an internal pull-down when not driven.
IM ⁽¹⁾	CPU Interface Mode	Ι	When IM is HIGH, the microprocessor port is in the multiplexed mode. When IM is LOW, the microprocessor port is in non-multiplexed mode. This pin is pulled low by an internal pull-down when not driven.
AD0-7 ⁽¹⁾	Address/Data Bus 0 to 7	I/O	These pins are the eight least significant data bits of the microprocessor port. In multiplexed mode, these pins are also the input address bits of the microprocessor port.

NOTE:

1. These pins are 5V tolerant.

PIN DESCRIPTION(CONTINUED):

SYMBOL	NAME	I/O	DESCRIPTION
D8-15 ⁽¹⁾	Data Bus 8-15	I/O	These pins are the eight most significant data bits of the microprocessor port.
DTA ⁽¹⁾	Data Transfer Acknowledgment	0	This active LOW output signal indicates that a data bus transfer is complete. When the bus cycle ends, this pin drives HIGH and then goes high-impedance, allowing for faster bus cycles with a weaker pull-up resistor. A pull-up resistor is required to hold a HIGH level when the pin is in high-impedance.
CCO ⁽¹⁾	Control Output	0	This is a 4.096, 8.192 or 16.384 Mb/s output containing 512, 1,024 or 2.048 bits per frame respectively. The level of each bit is determined by the CCO bit in the connection memory. See External Drive Control Section.
ODE ⁽¹⁾	Output Drive Enable	I	This is the output enable control for the TX0 to TX15 serial outputs. When ODE input is LOW and the OSB bit of the IMS register is LOW, TX0-15 are in a high-impedance state. If this input is HIGH, the TX0-15 output drivers are enabled. However, each channel may still be put into a high-impedance state by using the per channel control bit in the connection memory.

NOTE:

1. These pins are 5V tolerant.

FUNCTIONAL DESCRIPTION

The IDT7290820 is capable of switching up to $2,048 \times 2,048,64$ Kbit/s PCM or N x 64 Kbit/s channel data. The device maintains frame integrity in data applications and minimum throughput delay for voice applications on a per channel basis.

The serial input streams of the IDT7290820 can have a bit rate of 2.048, 4.096 or 8.192 Mb/s and are arranged in 125 μ s wide frames, which contain 32,64 or 128 channels respectively. The data rates on input and output streams are identical.

In Processor Mode, the microprocessor can access input and output timeslots on a per channel basis allowing for transfer of control and status information. The IDT7290820 automatically identifies the polarity of the frame synchronization input signal and configures the serial streams to either ST-BUS® or GCI formats.

With the variety of different microprocessor interfaces, IDT7290820 has provided an Input Mode pin (IM) to help integrate the device into different microprocessor based environments: Non-multiplexed or Multiplexed. These interfaces provide compatibility with multiplexed and Motorola non-multiplexed buses. The device can also resolve different control signals eliminating the use of glue logic necessary to convert the signals (R/W/WR, DS/RD, AS/ALE).

The frame offset calibration function allows users to measure the frame offset delay using a frame evaluation pin (FE). The input offset delay can be programmed for individual streams using internal frame input offset registers, see Table 11.

The internal loopback allows the TX output data to be looped around to the RX inputs for diagnostic purposes.

A functional Block Diagram of the IDT7290820 is shown in Figure 1.

DATA AND CONNECTION MEMORY

The received serial data is converted to parallel format by internal serialto-parallel converters and stored sequentially in the data memory. The 8KHz input frame pulse ($\overline{F0i}$) is used to generate channel and frame boundaries of the input serial data. Depending on the interface mode select (IMS) register, the usable data memory may be as large as 2,048 bytes.

Data to be output on the serial streams (TX0-15) may come from either the data memory or connection memory. For data output from data memory (connection mode), addresses in the connection memory are used. For data to be output from connection memory, the connection memory control bits must set the particular TX output in Processor Mode. One time-slot before the data is to be output, data from either connection memory or data memory is read internally. This allows enough time for memory access and parallel-to-serial conversion.

CONNECTION AND PROCESSOR MODES

In the Connection Mode, the addresses of the input source data for all output channels are stored in the connection memory. The connection memory is mapped in such a way that each location corresponds to an output channel on the output streams. For details on the use of the source address data (CAB and SAB bits), see Table 13 and Table 14. Once the source address bits are programmed by the microprocessor, the contents of the data memory at the selected address are transferred to the parallel-to-serial converters and then onto a TX output stream.

By having the each location in the connection memory specify an input channel, multiple outputs can specify the same input address. This can be a powerful tool used for broadcasting data.

In Processor Mode, the microprocessor writes data to the connection memory. Each location in the connection memory corresponds to a particular output stream and channel number and is transferred directly to the parallel-to-serial converter one time-slot before it is to be output. This data will be output on the TX streams in every frame until the data is changed by the microprocessor.

As the IDT7290820 can be used in a wide variety of applications, the device also has memory locations to control the outputs based on operating mode. Specifically, the IDT7290820 provides five per-channel control bits for the following functions: processor or connection mode, constant or variable delay, enables/three-state the TX output drivers and enables/disable the loopback function. In addition, one of these bits allows the user to control the CCO output.

If an output channel is set to a high-impedance state through the connection memory, the TX output will be in a high-impedance state for the duration of that channel. In addition to the per-channel control, all channels on the ST-BUS® outputs can be placed in a high impedance state by either pulling the ODE input pin low or programming the Output Stand-By (OSB) bit in the interface mode selection register. This action overrides the per-channel programming in the connection memory bits.

The connection memory data can be accessed via the microprocessor interface. The addressing of the devices internal registers, data and connection memories is performed through the address input pins and the Memory Select (MS) bit of the control register. For details on device addressing, see Software Control and Control Register bits description (Table 4, 6 and 7).

SERIAL DATA INTERFACE TIMING

The master clock frequency must always be twice the data rate. For serial data rates of 2.048, 4.096 or 8.192 Mb/s, the master clock (CLK) must be either at 4.096, 8.192 or 16.384 MHz respectively. The input and output stream data rates will always be identical.

The IDT7290820 provides two different interface timing modes ST-BUS[®]/ GCI and WFP (wide frame pulse). If the WFPS pin is high, the IDT7290820 is in the wide frame pulse (WFP) frame alignment mode.

In ST-BUS®/GCI mode, the input 8 KHz frame pulse can be in either ST-BUS® or GCI format. The IDT7290820 automatically detects the presence of an input frame pulse and identifies it as either ST-BUS® or GCI. In ST-BUS® format, every second falling edge of the master clock marks a bit boundary and the data is clocked in on the rising edge of CLK, three quarters of the way into the bit cell, see Figure 7. In GCI format, every second rising edge of the master clock marks the bit boundary and data is clocked in on the falling edge of CLK at three quarters of the way into the bit cell, see Figure 8.

WIDE FRAME PULSE (WFP) FRAME ALIGNMENT TIMING

When the device is in WFP frame alignment mode, the CLK input must be at 16.384 MHz, the FE/HCLK input is 4.096 MHz and the 8 KHz frame pulse is in ST-BUS[®] format. The timing relationship between CLK, HCLK and the frame pulse is shown in Figure 9.

When WFPS pin is high, the frame alignment evaluation feature is disabled. However, the frame input offset registers may still be programmed to compensate for the varying frame delays on the serial input streams.

SWITCHING CONFIGURATIONS

The IDT7290820 can operate at different speeds. To configure the maximum non-blocking switching data rate, the two DR bits in the IMS register are used. Following are the possible configurations:

2.048 Mb/s Serial Links (DR0=0, DR1=0)

When the 2.048 Mb/s data rate is selected, the device is configured with 16-input/16-output data streams each having 32, 64 Kbit/s channels each. This mode requires a CLK of 4.096 MHz and allows a maximum non-blocking capacity of 512×512 channels.

4.096 Mb/s Serial Links (DR0=1, DR1=0)

When the 4.096 Mb/s data rate is selected, the device is configured with 16-input/16-output data streams each having 64, 64 Kbit/s channels each. This mode requires a CLK of 8.192 MHz and allows a maximum non-blocking capacity of 1,024 x 1,024 channels.

8.192 Mb/s Serial Links (DR0=0, DR1=1)

When the 8.192 Mb/s data rate is selected, the device is configured with 16-input/16-output data streams each having 128, 64 Kbit/s channels each. This mode requires a CLK of 16.384 MHz and allows a maximum non-blocking capacity of 2,048 x 2,048 channels.

Table 1 summarizes the switching configurations and the relationship between different serial data rates and the master clock frequencies.

INPUT FRAME OFFSET SELECTION

Input frame offset selection allows the channel alignment of individual input streams to be offset with respect to the output stream channel alignment (i.e. $\overline{F0i}$). Although all input data comes in at the same speed, delays can be caused by variable path serial backplanes and variable path lengths which may be implemented in large centralized and distributed switching systems. Because data is often delayed, this feature is useful in compensating for the skew between clocks.

Each input stream can have its own delay offset value by programming the frame input offset registers (FOR). The maximum allowable skew is +4.5 master clock (CLK) periods forward with resolution of 1/2 clock period. The output frame offset cannot be offset or adjusted. See Figure 5, Table 11 and 12 for delay offset programming.

SERIAL INPUT FRAME ALIGNMENT EVALUATION

The IDT7290820 provides the frame evaluation (FE) input to determine different data input delays with respect to the frame pulse F0i.

A measurement cycle is started by setting the start frame evaluation (SFE) bit low for at least one frame. When the SFE bit in the IMS register is changed

Serial Interface Data Rate	Master Clock Required (MHz)	Matrix Channel Capacity			
2.048 Mb/s	4.096	512 x 512			
4.096 Mb/s	8.192	1,024 x 1,024			
8.192 Mb/s	16.384	2,048 x 2,048			

TABLE 1 — SWITCHING CONFIGURATION

from low to high, the evaluation starts. Two frames later, the complete frame evaluation (CFE) bit of the frame alignment register (FAR) changes from low to high to signal that a valid offset measurement is ready to be read from bits 0 to 11 of the FAR register. The SFE bit must be set to zero before a new measurement cycle started.

In ST-BUS[®] mode, the falling edge of the frame measurement signal (FE) is evaluated against the falling edge of the ST-BUS[®] frame pulse. In GCI mode, the rising edge of FE is evaluated against the rising edge of the GCI frame pulse. See Table 10 & Figure 4 for the description of the frame alignment register.

This feature is not available when the WFP Frame Alignment mode is enabled (i.e., when the WFPS pin is connected to VCC).

MEMORY BLOCK PROGRAMMING

The IDT7290820 provides users with the capability of initializing the entire connection memory block in two frames. To set bits 11 to 15 of every connection memory location, first program the desired pattern in bits 5 to 9 of the IMS register.

The block programming mode is enabled by setting the memory block program (MBP) bit of the control register high. When the block programming enable (BPE) bit of the IMS register is set to high, the block programming data will be loaded into the bits 11 to 15 of every connection memory location. The other connection memory bits (bit 0 to bit 10) are loaded with zeros. When the memory block programming is complete, the device resets the BPE bit to zero.

LOOPBACK CONTROL

The loopback control (LPBK) bit of each connection memory location allows the TX output data to be looped backed internally to the RX input for diagnostic purposes.

If the LPBK bit is high, the associated TX output channel data is internally looped back to the RX input channel (i.e., data from TX n channel m routes to the RX n channel m internally); if the LPBK bit is low, the loopback feature is disabled. For proper per-channel loopback operation, the contents of frame delay offset registers must be set to zero.

DELAY THROUGH THE IDT7290820

The switching of information from the input serial streams to the output serial streams results in a throughput delay. The device can be programmed to perform time-slot interchange functions with different throughput delay capabilities on the per-channel basis. For voice applications, variable throughput delay is best as it ensures minimum delay between input and output data. In wideband data applications, constant throughput delay is best as the frame integrity of the information is maintained through the switch.

The delay through the device varies according to the type of throughput delay selected in the \overline{V}/C bit of the connection memory.

VARIABLE DELAY MODE (\overline{V}/C BIT = 0)

In this mode, the delay is dependent only on the combination of source and destination channels and is independent of input and output streams. The minimum delay achievable in the IDT7290820 is three time-slots. If the input channel data is switched to the same output channel (channel n, frame p), it will be output in the following frame (channel n, frame p+1). The same is true if input channel n is switched to output channel n+1 or n+2. If the input channel n is switched to output channel n+3, n+4,..., the new output data will appear in the same frame. Table 2 shows the possible delays for the IDT7290820 in the variable delay mode.

CONSTANT DELAY MODE (\overline{V}/C BIT = 1)

In this mode, frame integrity is maintained in all switching configurations by making use of a multiple data memory buffer. Input channel data is written into the data memory buffers during frame n will be read out during frame n+2. In the IDT7290820, the minimum throughput delay achievable in the constant delay mode will be one frame. For example, in 2.048 Mb/s mode, when input time-slot31 is switched to output time-slot0. The maximum delay of94 time-slots of delay occurs when time-slot0 in a frame is switched to time-slot31 in the frame. See Table 3.

MICROPROCESSOR INTERFACE

The IDT7290820 provides a parallel microprocessor interface for multiplexed or non-multiplexed bus structures. This interface is compatible with Motorola non-multiplexed and multiplexed buses.

If the IM pin is low a Motorola non-multiplexed bus should be connected to the device. If the IM pin is high, the device monitors the AS/ALE and DS/\overline{RD} to determine what mode the IDT7290820 should operate in.

If DS/RD is low at the rising edge of AS/ALE, then the mode 1 multiplexed timing is selected. If DS/RD is high at the rising edge of AS/ALE, then the mode 2 multiplexed bus timing is selected.

For multiplexed operation, the required signals are the 8-bit data and address (AD0-AD7), 8-bit Data (D8-D15), Address strobe/Address latch enable (AS/ALE), Data strobe/Read (DS/RD), Read/Write/Write (R/W/WR), Chip select (\overline{CS}) and Data transfer acknowledge (\overline{DTA}). See Figure 12 and Figure 13 for multiplexed parallel microport timing.

For the Motorola non-multiplexed bus, the required signals are the 16-bit data bus (AD0-AD7, D8-D15), 8-bit address bus (A0-A7) and 4 control lines (\overline{CS} , DS, R/W and \overline{DTA}). See Figure 14 and 15 for Motorola non-multiplexed microport timing.

The IDT7290820 microport provides access to the internal registers, connection and data memories. All locations provide read/write access except for the data memory and the frame alignment register which are read only.

MEMORY MAPPING

The address bus on the microprocessor interface selects the internal registers and memories of the IDT7290820.

If the A7 address input is low, then A6 through A0 are used to address the interface mode selection (IMS), control (CR), frame alignment (FAR) and frame input offset (FOR) registers (Table 4). If the A7 is high, then A6 through A0 are used to select 32, 64, or 128 locations corresponding to data rate of the ST-BUS[®]. The address input lines and the stream address bits (STA) of the control register allow access to the entire data and connection memories. The control and IMS registers together control all the major functions of the device, see Figure 3.

As explained in the Serial Data Interface Timing and Switching Configurations sections, after system power-up, the IMS register should be programmed immediately to establish the desired switching configuration.

The data in the control register consists of the memory block programming bit (MBP), the memory select bit (MS) and the stream address bits (STA). As explained in the Memory Block Programming section, the MBP bit allows the entire connection memory block to be programmed. The memory select bit is used to designate the connection memory or the data Memory. The stream address bits select internal memory subsections corresponding to input or output serial streams.

The data in the IMS register consists of block programming bits (BPD0-BPD4), block programming enable bit (BPE), output stand by bit (OSB), start frame evaluation bit (SFE) and data rate selection bits (DR0-1). The block programming and the block programming enable bits allows users to program the entire connection memory (see Memory Block Programming section). If the ODE pin is low, the OSB bit enables (if high) or disables (if low) all ST-BUS[®] output drivers. If the ODE pin is high, the contents of the OSB bit is ignored and all TX output drivers are enabled.

CONNECTION MEMORY CONTROL

The CCO pin is a 4.096, 8.192 or 16.384 Mb/s output, which carries 512, 1,024 or 2,048 bits, respectively. The contents of the CCO bit of each connection memory location are output on the CCO pin once every frame. The contents of the CCO bits of the connection memory are transmitted sequentially on to the CCO pin and are synchronous with the data rates on the other serial streams.

The CCO bit is output one channel before the corresponding channel on the serial streams. For example, in 2.048 Mb/s mode (32 channels per frame), the contents of the CCO bit in position 0 (TX0, CH0) of the connection memory is output on the first clock cycle of channel 31 through CCO pin. The contents of the CCO bit in position 32 (TX1, CH0) of the connection memory is output on the second clock cycle of channel 31 via CCO pin.

If the ODE pin or the OSB bit is high, the OE bit of each connection memory location controls the output drivers-enables (if high) or disables (if low). See Table 5 for detail.

The processor channel (PC) bit of the connection memory selects between Processor Mode and Connection Mode. If high, the contents of the connection memory are output on the TX streams. If low, the stream address bit (SAB) and the channel address bit (CAB) of the connection memory defines the source information (stream and channel) of the time-slot that will be switched to the output from data memory.

The \overline{V}/C (Variable/Constant Delay) bit in each connection memory location allows the per-channel selection between variable and constant throughput delay modes.

If the LPBK bit is high, the associated TX output channel data is internally looped back to the RX input channel (i.e., RX n channel m data comes from the TX n channel m). If the LPBK bit is low, the loopback feature is disabled. For proper per-channel loopback operation, the contents of the frame delay offset registers must be set to zero.

INITIALIZATION OF THE IDT7290820

After power up, the state of the connection memory is unknown. As such, the outputs should be put in high impedance by holding the ODE low. While the ODE is low, the microprocessor can initialize the device, program the active paths, and disable unused outputs by programming the OE bit in connection memory. Once the device is configured, the ODE pin (or OSB bit depending on initialization) can be switched.

zero ble v byte:	ed. When A7 =1, /ia A0-A6 at any c	up to 128 bytes a one instant. Of w	Control Register when A7-A0 are all are randomly accessa hich stream these mined by the state of		CR _b 3 CR _b 2	CR _b 1	CR _b 0			
		Connect	ion Memory		↓ \					١
			Data Memory			CR _b 3	CR _b 2	CR _b 1	CR _b 0	Stream
	Channel 0	Channel 1	Channel 2	Channel 12	7	0 ·	0	0	0	0
	Channel 0	Channel 1	Channel 2	Channel 12	7	0	0	0	1	1
	Channel 0	Channel 1	Channel 2	Channel 12	7	0	0	1	0	2
	Channel 0	Channel 1	Channel 2	Channel 12	7	0	0	1	1	3
	Channel 0	Channel 1	Channel 2	Channel 12	7	0	1	0	0	4
	Channel 0	Channel 1	Channel 2	Channel 12	7	0	1	0	1	5
	Channel 0	Channel 1	Channel 2	Channel 12	7	0	1	1	0	6
	Channel 0	Channel 1	Channel 2	Channel 12	7	0	1	1	1	7
	Channel 0	Channel 1	Channel 2	Channel 12	7	- 1 ·	0	0	0	8
	Channel 0	Channel 1	Channel 2	Channel 12	7	- 1	0	0	1	9
	Channel 0	Channel 1	Channel 2	Channel 12	7	. 1	0	1	0	10
	Channel 0	Channel 1	Channel 2	Channel 12	7	. 1	0	1	1	11
	Channel 0	Channel 1	Channel 2	Channel 12	7	- 1	1	0	0	12
	Channel 0	Channel 1	Channel 2	Channel 12	7	- 1	1	0	1	13
	Channel 0	Channel 1	Channel 2	Channel 12	7	. 1	1	1	0	14
	Channel 0	Channel 1	Channel 2	Channel 12	7	1	1	1	1	15
I						A	Dite			
	10000000	10000001	10000010	11111111	External	Address	s Bits	A7-A	40	5713 dpw06

5713 drw06

Figure 3. Addressing Internal Memories

TABLE 2—VARIABLE THROUGHPUT DELAY VALUE

Input Rate		Delay for Variable Throughput Delay Mode (m – output channel number) (n – input channel number)								
	m < n m = n, n+1, n+2 m > n+2									
2.048 Mb/s	32-(n-m) time-slots	m-n+32 time slots	m-n time-slots							
4.096 Mb/s	64-(n-m) time-slots	m-n+64 time-slots	m-n time slots							
8.192 Mb/s	128-(n-m) time-slots m-n time-slots m-n time-slots									

TABLE 3—CONSTANT THROUGHPUT DELAY VALUE

Input Rate	Delay for Constant Throughput Delay Mode (m – output channel number)
	(n – output channel number)
2.048 Mb/s	32 + (32 – n) + m time-slots
4.096 Mb/s	64 + (64 – n) + m time-slots
8.192 Mb/s	128 + (128 – n) + m time-slots

TABLE 4—INTERNAL REGISTER AND ADDRESS MEMORY MAPPING

A7 ⁽¹⁾	A6	A5	A 4	A3	A2	A 1	A0	Location			
0	0	0	0	0	0	0	0	Control Register, CR			
0	0	0	0	0	0	0	1	Interface Mode Selection Register, IMS			
0	0	0	0	0	0	1	0	Frame Alignment Register, FAR			
0	0	0	0	0	0	1	1	Frame Input Offset Register 0, FOR0			
0	0	0	0	0	1	0	0	Frame Input Offset Register 1, FOR1			
0	0	0	0	0	1	0	1	Frame Input Offset Register 2, FOR2			
0	0	0	0	0	1	1	0	Frame Input Offset Register 3, FOR3			
1	0	0	0	0	0	0	0	Ch0			
1	0	0	0	0	0	0	1	Ch1			
1	0	0									
1	0	0	1	1	1	1	0	Ch30			
1	0	0	1	1	1	1	1	Ch31 (Note 2)			
1	0	1	0	0	0	0	0	Ch32			
1	0	1	0	0	0	0	1	Ch33			
1	0	1									
1	0	1	1	1	1	1	0	Ch62			
1	0	1	1	1	1	1	1	Ch63 (Note 3)			
1	1	0	0	0	0	0	0	Ch64			
1	1	0	0	0	0	0	1	Ch65			
1	1	0									
1	1	1	1	1	1	1	0	Ch126			
1	1	1	1	1	1	1	1	Ch127 (Note 4)			

Notes:

1. Bit A7 must be high for access to data and connection memory positions. Bit A7 must be low for access to registers.

2. Channels 0 to 31 are used when serial interface is at 2.048 Mb/s mode

3. Channels 0 to 63 are used when serial interface is at 4.096 Mb/s mode.

4. Channels 0 to 127 are used when serial interface is at 8.192 Mb/s mode.

TABLE 5-OUTPUT HIGH IMPEDANCE CONTROL

OE bit in Connection	ODE pin	OSB bit in IMS	TX Output Driver				
Memory		Register	Status				
0	Don't Care	Don't Care	Per Channel				
			High-Impedance				
1	0	0	High-Impedance				
1	0	1	Enable				
1	1	1	Enable				
1	1	0	Enable				

TABLE 6—CONTROL REGISTER (CR) BITS

Read/Write Address: 00н, Reset Value: 0000н.																
15	14 13 12 1		11	10	9	8	7	6	5	4	3	2	1	0		
Bit Name Description																
15-6	Unus				Must be zero for normal operation.											
5	MBP (Merr	nory Bloc	k Progran		Vhen 1, the /lemory high								r the prog	grammin	g of Conne	ection
4	MS (Men	nory Sele	ect)	f	When 0, connection memory is selected for read or write operations. When 1, the data memory is selected for read operations and connection memory is selected for write operations. (No microprocessor write operation is allowed for the data memory).											
3-0	STA3-0 (Stream Address Bits) The binary value expressed by these bits refers to the input or output data stream, which corresponds to the subsection of memory made accessible for subsequent operations. (STA3 = MSB, STA0 = LSB)															

TABLE 7—VALID ADDRESS LINES FOR DIFFERENT BIT RATES

Input/Output	Valid Address Lines					
Data Rate						
2.048 Mb/s	A4, A3, A2, A1, A0					
4.096 Mb/s	A5, A4, A3, A2, A1, A0					
8.192 Mb/s	A6, A5, A4, A3, A2, A1, A0					

ABLE	E 8 —	-IN7	ERF	FACE	MO	DE S	ELEC	СТІО	N (II	MS) F	REG	STE	R BI	TS	
Read/Write Address: 01н,															
Reset	/alue:		0000	н.											
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Bit		Nam	ie							Descrip	otion				
15-10	Unuse	d			Must be	zero fo	r normal	operatio	n.						
9-5	`	-	nming [Data)	These bits carry the value to be loaded into the connection memory block whenever the memory block programming feature is activated. After the MBP bit in the control register is set to 1 and the BPE bit is set to 1, the contents of the bits BPD4-0 are loaded into bit 15 and 11 of the connection memory. Bit 10 t bit 0 of the connection memory are set to 0.										
4	BPE (Begin Block Programming Enable)A zero to one transition of this bit enables the memory block programming function. The BPE and BPD4-0 bits in the IMS register have to be defined in the same write operation. Once the BPE bit is s HIGH, the device requires two frames to complete the block programming. After the programming function has finished, the BPE bit returns to zero to indicate the operation is completed. When the BPE = 1, to or MBP can be set to 0 to ensure proper operation. When BPE = 1, the other bit in the IMS register must not be changed for two frames to ensure proper operation.														
3	OSB (Outpu	it Stand	By)		When ODE = 0 and OSB = 0, the output drivers of TX0 to TX15 are in high impedance mode. When ODE = 0 and OSB = 1, the output driver of TX0 to TX15 function normally. When ODE = 1, TX0 to TX15 output drivers function normally.										
2	SFE A zero to one transition in this bit starts the frame evaluation procedure. When the CFE bit in the register changes from zero to one, the evaluation procedure stops. To start another fame evaluation cycle, set this bit to zero for at least one frame.														
1-0	DR0-1 (Data F	Rate Sel	lect)		Input/O	utput da	ta rate se	election.	SeeTab	ole9ford	etailed p	rogramn	ning.		

_ . ----

TABLE 9—SERIAL DATA RATE SELECTION (16 INPUT x 16 OUTPUT)

DR1	DR0	Data Rate Selected	Master Clock Required					
0	0	2.048 Mb/s	4.096 MHz					
0	1	4.096 Mb/s	8.192 MHz					
1	0	8.192 Mb/s	16.384 MHz					
1	1	Reserved	Reserved					

TABLE 10—FRAME ALIGNMENT REGISTER (FAR) BITS

	d/Write Address: et Value:	02н, 0000н.											
15	14 13	12 1	1 10	98	7	6	5	4	3	2	1	0	
0	0	CFE FD	11 FD10	FD9 FD	8 FD7	FD6	FD5	FD4	FD3	FD2	FD1	FD0	
Bit	Name						Descrij	otion					
15-13	Unused		Mustbez	zero for norma	l operation.								
12	CFE (Complete Frame	Evaluation)		E = 1, the fran								valid frame a	alignment
11	FD11 (Frame Delay Bit	11)		The falling edge of FE (or rising edge for GCI mode) is sampled during the CLK-high phase (FD11 = 1) or during the CLK-low phase (FD11 = 0). This bit allows the measurement resolution to $\frac{1}{2}$ CLK cycle.									
10-0	FD10-0 (Frame Delay Bits	-		r during the CLK-low phase (FD11 = 0). This bit allows the measurement resolution to $\frac{1}{2}$ CLK cycle. he binary value expressed in these bits refers to the measured input offset value. These bits are rest to ero when the <u>SFE</u> bit of the IMS register changes from 1 to 0. (FD10 – MSB, FD0 – LSB)									

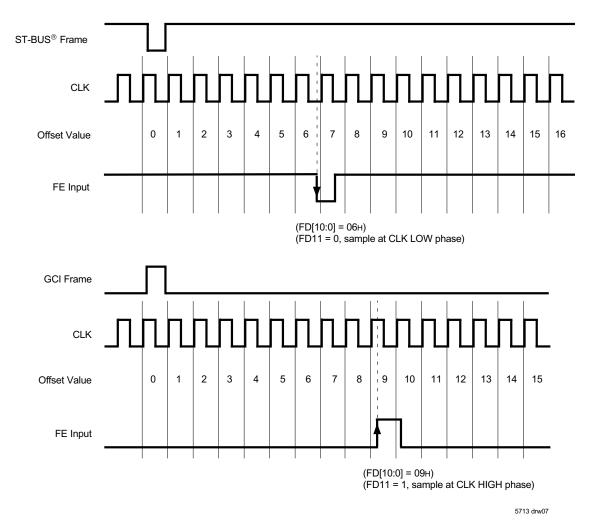


Figure 4. Example for Frame Alignment Measurement

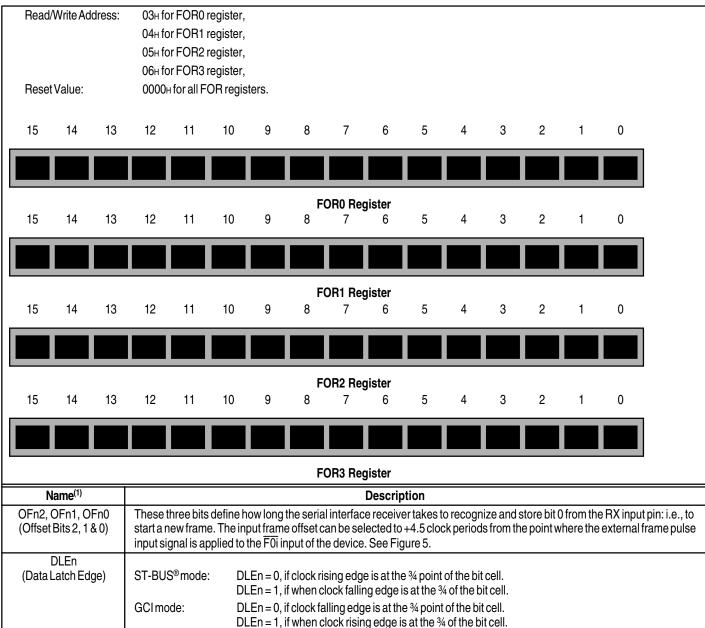


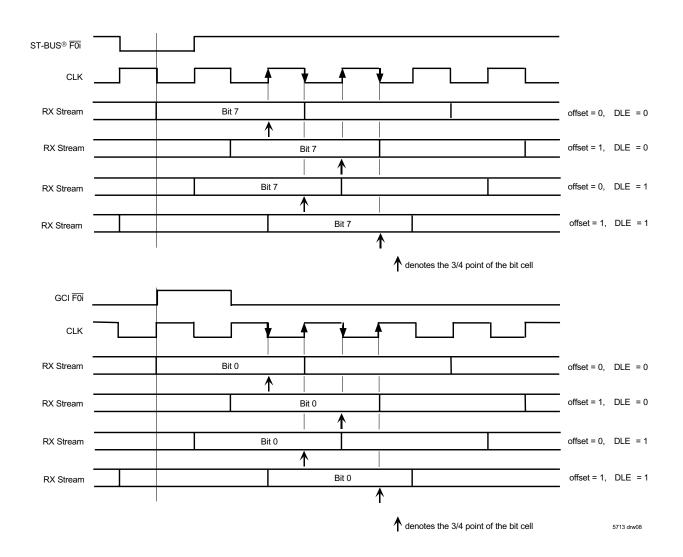
TABLE 11—FRAME INPUT OFFSET REGISTER (FOR) BITS

NOTE:

1. n denotes an input stream number from 0 to 15.

TABLE 12—OFFSET BITS (OFn2, OFn1, OFn0, DLEn) & FRAME DELAY BITS (FD11, FD2-0)

Input Stream Offset			nt Result from Delay Bits				ponding etBits	
Ulisel	FD11	FD2	FD1	FD0	OFn2	OFn1	OFn0	DLEn
No clock period shift (Default)	1	0	0	0	0	0	0	0
+ 0.5 clock period shift	0	0	0	0	0	0	0	1
+ 1.0 clock period shift	1	0	0	1	0	0	1	0
+ 1.5 clock period shift	0	0	0	1	0	0	1	1
+2.0 clock period shift	1	0	1	0	0	1	0	0
+2.5 clock period shift	0	0	1	0	0	1	0	1
+ 3.0 clock period shift	1	0	1	1	0	1	1	0
+ 3.5 clock period shift	0	0	1	1	0	1	1	1
+4.0 clock period shift	1	1	0	0	1	0	0	0
+4.5 clock period shift	0	1	0	0	1	0	0	1



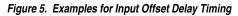


TABLE 13—CONNECTION MEMORY BITS

15 LPBK		10 9 8 7 6 5 4 3 2 1 0 SAB3 SAB2 SAB1 SAB0 CAB6 CAB5 CAB4 CAB3 CAB2 CAB1 CAB0			
Bit	Name	Description			
15	LPBK (Per Channel Loopback)	When 1, the RX n channel m data comes from the TX n channel m. For proper per channel loopback operations, set the delay offset register bits OFn[2:0] to zero for the streams which are in the loopback mode.			
14	V/C (Variable/Constant Throughput Delay)	This bit is used to select between the variable (LOW) and constant delay (HIGH) mode on a per-channel basis.			
13	PC (Processor Channel)	When 1, the contents of the connection memory are output on the corresponding output channel and stream. Only the lower byte (bit 7 – bit 0) will be output to the TX output pins. When 0, the contents of the connection memory are the data memory address of the switched input channel and stream.			
12	CCO (Control Channel Output)	This bit is output on the CCO pin one channel early. The CCO bit for stream 0 is output first.			
11					
10-8,7 ⁽¹⁾	SAB3-0 (Source Stream Address Bits)	The binary value is the number of the data stream for the source of the connection.			
6-0 ⁽¹⁾	CAB6-0 (Source Channel Address Bits)	The binary value is the number of the channel for the source of the connection.			

NOTE:

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1. If bit 13 (PC) of the corresponding connection memory location is 1 (device in processor mode), then these entire 8 bits (SAB0, CAB6 - CAB0) are output on the output channel and stream associated with this location.

TABLE 14—CAB BIT PROGRAMMING FOR DIFFERENT DATA RATES

Data Rate	CAB Bits Used to Determine the Source Channel of the Connection					
2.048 Mb/s	CAB4 to CAB0 (32 channel/input stream)					
4.096 Mb/s	CAB5 to CAB0 (64 channel/input stream)					
8.192 Mb/s	CAB6 to CAB0 (128 channel/input stream)					

JTAG SUPPORT

The IDT7290820 JTAG interface conforms to the Boundary-Scan standard IEEE-1149.1. This standard specifies a design-for-testability technique called Boundary-Scan Test (BST). The operation of the boundary-scan circuitry is controlled by an external test access port (TAP) Controller.

TEST ACCESS PORT (TAP)

The Test Access Port (TAP) provides access to the test functions of the IDT7290820. It consists of three input pins and one output pin.

•Test Clock Input (TCK)

TCK provides the clock for the test logic. The TCK does not interfere with any on-chip clock and thus remain independent. The TCK permits shifting of test data into or out of the Boundary-Scan register cells concurrently with the operation of the device and without interfering with the on-chip logic.

•Test Mode Select Input (TMS)

The logic signals received at the TMS input are interpreted by the TAP Controller to control the test operations. The TMS signals are sampled at the rising edge of the TCK pulse. This pin is internally pulled to Vcc when it is not driven from an external source.

•Test Data Input (TDI)

Serial input data applied to this port is fed either into the instruction register or into a test data register, depending on the sequence previously applied to the TMS input. Both registers are described in a subsequent section. The received input data is sampled at the rising edge of TCK pulses. This pin is internally pulled to Vcc when it is not driven from an external source.

•Test Data Output (TDO)

Depending on the sequence previously applied to the TMS input, the contents of either the instruction register or data register are serially shifted out towards the TDO. The data out of the TDO is clocked on the falling edge of the TCK pulses. When no data is shifted through the boundary scan cells, the TDO driver is set to a high impedance state.

•Test Reset (TRST)

Reset the JTAG scan structure. This pin is internally pulled to VCC.

INSTRUCTION REGISTER

In accordance with the IEEE 1149.1 standard, the IDT7290820 uses public instructions. The IDT7290820 JTAG Interface contains a two-bit instruction register. Instructions are serially loaded into the instruction register from the TDI when the TAP Controller is in its shifted-IR state. Subsequently, the instructions are decoded to achieve two basic functions: to select the test data register that may operate while the instruction is current, and to define the serial test data register path, which is used to shift data between TDI and TDO during data register scanning. See Table below for instruction decoding.

Value	Instruction	Function
11	Bypass	Select ByPass Register
10	Sample/Period	Select Boundry Scan Register
01	Sample/Period	Select Boundry Scan Register
00	EXTEST	Select Boundry Scan Register
	1	

JTAG Instruction Register Decoding

TEST DATA REGISTER

As specified in IEEE 1149.1, the IDT7290820 JTAG Interface contains two test data registers:

•The Boundary-Scan register

The Boundary-Scan register consists of a series of Boundary-Scan cells arranged to form a scan path around the boundary of the IDT7290820 core logic.

•The Bypass Register

The Bypass register is a single stage shift register that provides a one-bit path from TDI to its TDO. The IDT7290820 boundary scan register contains 118 bits. Bit 0 in Table 15 Boundary Scan Register is the first bit clocked out. All three-state enable bits are active high.

TABLE 15—BOUNDARY SCAN REGISTER BITS

	Bounda	ary Scan Bit 0 to	bit 117		Bounda	ry Scan Bit 0 to	bit 117
Device Pin	Three-State	Output	Input	Device Pin	Three-State	Output	Input
	Control	Scan Cell	Scan Cell		Control	Scan Cell	Scan Cell
TX7	0	1		A4			76
TX6	2	3		A3			77
TX5	4	5		A2			78
TX4	6	7		A1			79
TX3	8	9		A0			80
TX2	10	11		WFPS			81
TX1	12	13		RESET			82
TX0	14	15		CLK			83
ODE			16	FE/HCLK			84
ССО	17	18		F0i			85
DTA		19		RX15			86
D15	20	21	22	RX14			87
D14	23	24	25	RX13			88
D13	26	27	28	RX12			89
D12	29	30	31	RX11			90
D11	32	33	34	RX10			91
D10	35	36	37	RX9			92
D9	38	39	40	RX8			93
D8	41	42	43	RX7			94
AD7	44	45	46	RX6			95
AD6	47	48	49	RX5			96
AD5	50	51	52	RX4			97
AD4	53	54	55	RX3			98
AD3	56	57	58	RX2			99
AD2	59	60	61	RX1			100
AD1	62	63	64	RX0			101
AD0	65	66	67	TX15	102	103	
IM			68	TX14	104	105	
AD/ALE			69	TX13	106	107	
CS			70	TX12	108	109	
R/W/WR			71	TX11	110	111	
DS/RD			72	TX10	112	113	
A7			73	TX9	114	115	
A6			74	TX8	116	117	
A5			75				

Symbol	Parameter	Min.	Max.	Unit
Vcc	Supply Voltage		6.0	V
Vi	Voltage on Digital Inputs	GND -0.3	Vcc +0.3	V
lo	Current at Digital Outputs		20	mA
Ts	Storage Temperature	-65	+125	°C
PD	Package Power Dissapation		2	W

ABSOLUTE MAXIMUM RATINGS(1)

NOTE:

1. Exceeding these values may cause permanent damage. Functional operation under these conditions is not implied.

RECOMMENDED DC OPERATING CONDITIONS

Symbol	Parameter	Min.	Тур.	Max.	Units
Vcc	Positive Supply	4.75		5.25	٧
Vін	Input HIGH Voltage	2.4		Vcc	٧
VIL	Input LOW Voltage	GND	_	0.4	٧
Тор	Operating Temperature Commercial	-40	_	+85	°C

NOTE:

1. Voltages are with respect to ground unless other wise stated.

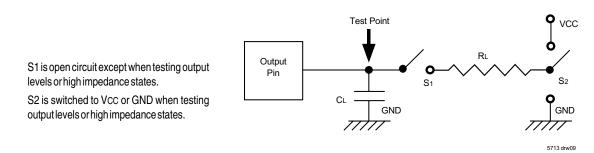
DC ELECTRICAL CHARACTERISTICS

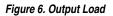
Symbol	Characteristics		Min.	Тур.	Max.	Units
ICC ⁽¹⁾	Supply Current	@ 2.048 Mb/s		16	25	mA
		@ 4.096 Mb/s	_	26	40	mA
		@ 8.192 Mb/s	—	50	75	mA
Vih	Input HIGH Voltage		2.0	—	_	V
Vol	Input LOW Voltage		—	_	0.8	V
IIL ⁽²⁾	Input Leakage (input p	ins)	—	_	15	μΑ
IBL	Input Leakage (I/O pir	is)			50	μΑ
Сі	Input Pin Capacitance				10	pF
loz	High-impedance Leak	age	_		5	μA
Vон	Output HIGH Voltage		2.4		_	V
Vol	Output LOW Voltage				0.4	V
Со	Output Pin Capacitano	се Се			10	pF

NOTE:

1. Outputs Unloaded.

2. For TDI, TMS, TCK, TRST, AS/ALE and IM pins, the maximum leakage current is 50µA.





AC ELECTRICAL CHARACTERISTICS - FRAME PULSE AND CLK

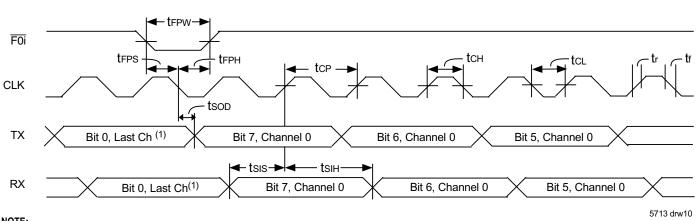
Symbol	Characteristics		Min.	Тур.	Max.	Units
tFPW	Frame Pulse Width (ST-BUS [®] , GCI) —	Bit rate = 2.048 Mb/s	26	_	295	ns
		Bit rate = 4.096 Mb/s	26	—	145	ns
		Bit rate = 8.192 Mb/s	26		80	ns
tFPS	Frame Pulse Setup time before CLK falling	(ST-BUS [®] or GCI)	10	_	—	ns
tFPH	Frame Pulse Hold Time from CLK falling (ST-BUS [®] or GCI)	16	_	_	ns
tCP	CLK Period —	Bit rate = 2.048 Mb/s	190	_	300	ns
		Bit rate = 4.096 Mb/s	110	—	150	ns
		Bit rate = 8.192 Mb/s	55	_	70	ns
tCH	CLK Pulse Width HIGH —	Bit rate = 2.048 Mb/s	85	_	150	ns
		Bit rate = 4.096 Mb/s	50	—	75	ns
		Bit rate = 8.192 Mb/s	20		40	ns
tCL	CLK Pulse Width LOW —	Bit rate = 2.048 Mb/s	85	—	150	ns
		Bit rate = 4.096 Mb/s	50	—	75	ns
		Bit rate = 8.192 Mb/s	20	_	40	ns
tr, tf	Clock Rise/Fall Time		—	_	10	ns
tHFPW	Wide Frame Pulse Width—	Bit rate = 8.192 Mb/s	195	_	295	ns
tHFPS	Frame Pulse Setup Time before HCLK fallir	g	10	_	150	ns
theph	Frame Pulse Hold Time from HCLK falling		20		150	ns
thcp	HCLK (4.096 MHz) Period —	Bit rate = 8.192 Mb/s	190	_	300	ns
thCH	HCLK (4.096 MHz) Pulse Width HIGH —	Bit rate = 8.192 Mb/s	85		150	ns
THCL	HCLK (4.096 MHz) Pulse Width LOW —	Bit rate = 8.192 Mb/s	85		150	ns
tHr, tHf	HCLK Rise/Fall Time				10	ns
tDIF	Delay between falling edge of HCLK and fa	ling edge of CLK	-10		10	ns

AC ELECTRICAL CHARACTERISTICS - SERIAL STREAMS (1)

Symbol	Characteristics	Min.	Тур.	Max.	Unit	Test Conditions
tsis	RX Setup Time	0			ns	
tsiH	RX Hold Time	20		_	ns	
tSOD	TX Delay – Active to Active	—		39	ns	C _L = 30pF
		—		58	ns	C _L = 200pF
tDZ	TX Delay – Active to High-Z	_	—	37	ns	$R_L = 1K\Omega, C_L = 200pF$
tzd	TX Delay – High-Z to Active	—		37	ns	$R_L = 1K\Omega, C_L = 200pF$
tODE	Output Driver Enable (ODE) Delay	—		37	ns	$R_L = 1K\Omega, C_L = 200pF$
txcD	CCO Output Delay	_		48	ns	C _L = 30pF
			—	58	ns	C _L = 200pF

NOTE:

1. High Impedance is measured by pulling to the appropriate rail with R₁, with timing corrected to cancel time taken to discharge C₁.



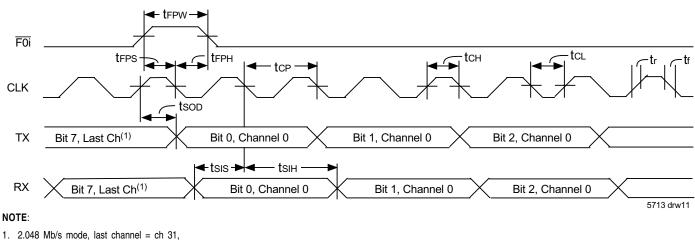


1. 2.048 Mb/s mode, last channel = ch 31,

4.096 Mb/s mode, last channel = ch 63,

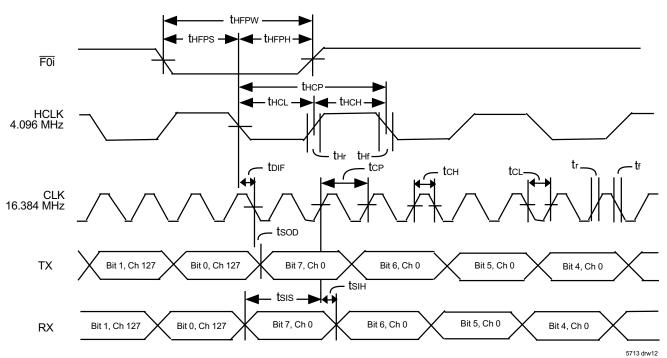
8.192 Mb/s mode, last channel = ch 127.

Figure 7. ST-BUS® Timing for 2.048 Mb/s and High Speed Serial Interface at 4.096 Mb/s or 8.192 Mb/s, when WFPS pin = 0.



2.048 Mb/s mode, last channel = ch 31,
 4.096 Mb/s mode, last channel = ch 63,
 8.192 Mb/s mode, last channel = ch 127.

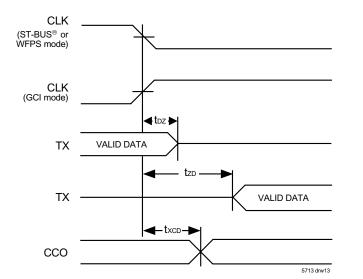




NOTE:

1. High Impedance is measured by pulling to the appropriate rail with R₁, with timing corrected to cancel time taken to discharge C₁.





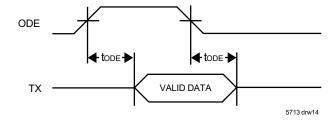


Figure 10. Serial Output and External Control

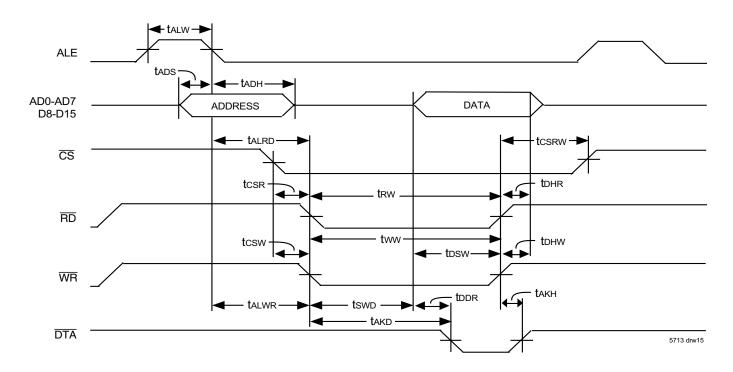


AC ELECTRICAL CHARACTERISTICS - MULTIPLEXED BUS TIMING (INTEL)

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
talw	ALE Pulse Width	20	—	—	ns	
tads	Address Setup from ALE falling	10			ns	
TADH	Address Hold from ALE falling	10			ns	
t ALRD	RD Active after ALE falling	10	—	—	ns	
tDDR	Data Setup from DTA LOW on Read	10	_		ns	C∟= 150pF
tCSRW	CS Hold after RD/WR	0			ns	
tRW	RD Pulse Width (Fast Read)	_	80	—	ns	
tCSR	CS Setup from RD	0	_		ns	
tDHR ⁽¹⁾	Data Hold after RD	10	_	75	ns	C∟= 150pF, R∟= 1K
tww	WR Pulse Width (Fast Write)	45	—	—	ns	
talwr	WR Delay after ALE falling	3	_	—	ns	
tCSW	CS Setup from WR	0			ns	
tDSW	Data Setup from WR (Fast Write)	20	_	_	ns	
tswD	Valid Data Delay on Write (Slow Write)	_	_	122	ns	
tDHW	Data Hold after WR Inactive	5	_	_	ns	
takd	Acknowledgment Delay:					
	Reading/Writing Registers			50/60	ns	CL = 150pF
	Reading/Writing Memory— @ 2.048 Mb/s @ 4.096 Mb/s			760/780 400/420	ns ns	C∟ = 150pF C∟ = 150pF
1	@ 8.192 Mb/s		45	220/240	ns	CL = 150pF
takh ⁽¹⁾	Acknowledgment Hold Time	—	45	80	ns	C∟= 150pF, R∟= 1K

NOTE:

1. High Impedance is measured by pulling to the appropriate rail with R_L , with timing corrected to cancel time taken to discharge C_L .



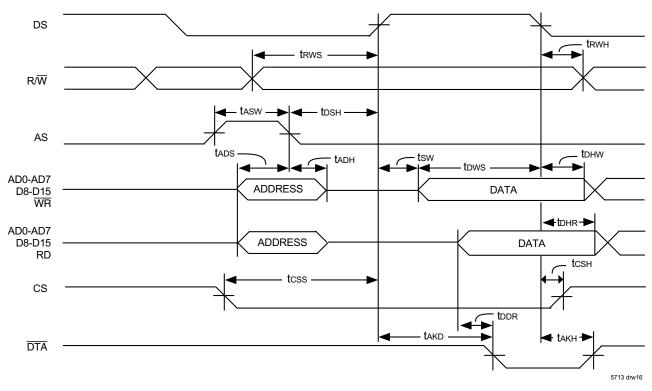


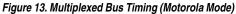
AC ELECTRICAL CHARACTERISTICS - MULTIPLEXED BUS TIMING (MOTOROLA)

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
tasw	ALE Pulse Width	80		—	ns	
tads	Address Setup from AS falling	10		—	ns	
tadh	Address Hold from AS falling	10		—	ns	
tDDR	Data Setup from DTA LOW on Read	10		_	ns	C∟= 150pF
tCSH	CS Hold after DS falling	0		—	ns	
tcss	CS Setup from DS rising	0		_	ns	
tDHW	Data Hold after Write	10		_	ns	
tDWS	Data Setup from DS – Write (Fast Write)	25		_	ns	
tSWD	Valid Data Delay on Write (Slow Write)			122	ns	
tRWS	R/W Setup from DS Rising	60		_	ns	
tRWH	R/W Hold from DS Rising	10		_	ns	
tDHR ⁽¹⁾	Data Hold after Read	10	50	75	ns	C∟= 150pF, R∟= 1K
tDSH	DS Delay after AS falling	10			ns	
takd	Acknowledgment Delay:					
	Reading/Writing Registers			55/60	ns	C∟= 150pF
	Reading/Writing Memory— @ 2.048 Mb/s			760/780	ns	C∟= 150pF
	@ 4.096 Mb/s			400/420	ns	C∟= 150pF
	@ 8.192 Mb/s			220/240	ns	C∟ = 150pF
takh ⁽¹⁾	AcknowledgmentHoldTime		45	80	ns	C∟= 150pF, R∟= 1K

NOTE:

1. High Impedance is measured by pulling to the appropriate rail with R₁, with timing corrected to cancel time taken to discharge C₁.





AC ELECTRICAL CHARACTERISTICS-MOTOROLA NON-MULTIPLEXED BUS MODE

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
tcss	CS Setup from DS falling	0		—	ns	
tRWS	R/W Setup from DS falling	10		—	ns	
tads	Address Setup from DS falling	2		—	ns	
tCSH	CS Hold after DS rising	0	_	_	ns	
tRWH	R/W Hold after DS Rising	5		—	ns	
tadh	Address Hold after DS Rising	5	—	—	ns	
tDDR	Data Setup from DTA LOW on Read	0		—	ns	C∟= 150pF
1DHR	Data Hold on Read	10	50	75	ns	C∟= 150pF, R∟ = 1K
tDSW	Data Setup on Write (Fast Write)	20		—	ns	
tSWD	Valid Data Delay on Write (Slow Write)	_	_	122	ns	
tDHW	Data Hold on Write	8	_	_	ns	
takd	Acknowledgment Delay:					
	Reading/Writing Registers			55/60	ns	C∟= 150pF
	Reading/Writing Memory— @ 2.048 Mb/s @ 4.096 Mb/s @ 8.192 Mb/s			760/780 400/420 220/240	ns ns ns	C∟ = 150pF C∟ = 150pF C∟ = 150pF
takh ⁽¹⁾	Acknowledgment Hold Time		45	80	ns	C∟= 150pF, R∟ = 1K

NOTE:

1. High Impedance is measured by pulling to the appropriate rail with R₁, with timing corrected to cancel time taken to discharge C₁.

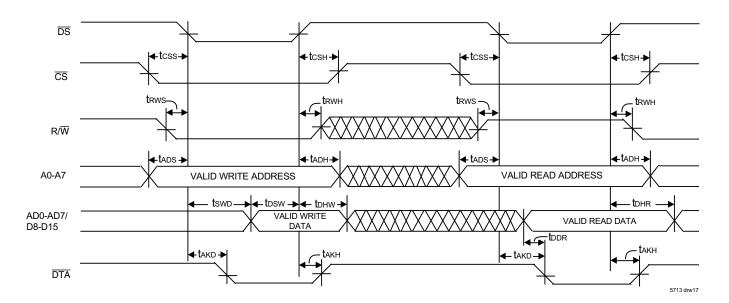


Figure 14. Motorola Non-Multiplexed Asyncronous Bus Timing

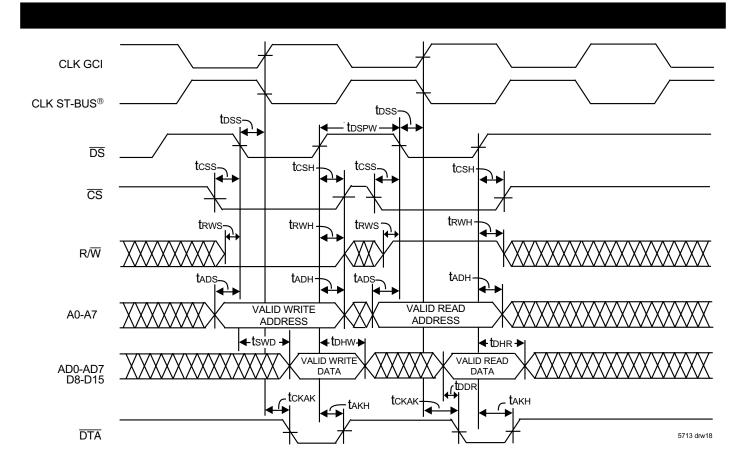
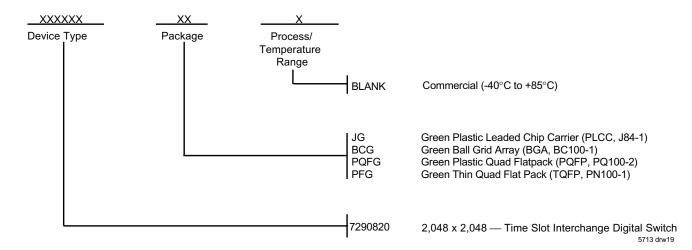


Figure 15. Motorola Non-Multiplexed Syncronous Bus Timing

ORDERING INFORMATION



DATASHEET DOCUMENT HISTORY

5/23/2000	pgs.1, 3, 18 and 25.	03/02/09 pg. 26 Removed "IDT" from ordering part number.
8/15/2000	pgs.1, 2, 3, 6, 13 and 25.	07/10/14 pg. 27 Removed Leaded devices
9/22/2000	pgs. 3 and 13.	
12/22/2000	pgs. 7, 12, 18, 21, 22, 23, 24 and 25.	
01/24/2001	pg. 1, 16 and 18.	
07/09/2001	pgs. 4, 5, 12 and 25.	

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